

S13496

High sensitivity, photosensitive area with minute pixels

The S13496 is a high sensitivity CMOS linear image sensor using a photosensitive area with minute pixels. It has a long photosensitive area (effective photosensitive length: 28.672 mm) consisting of 4096 pixels, each with a pixel size of $7 \times 200 \mu\text{m}$. Surface mount type (S13496-20) is also available.

Features

- Pixel size: $7 \times 200 \mu\text{m}$
- 4096 pixels
- Effective photosensitive area length: 28.672 mm
- High sensitivity: $650 \text{ V}/(\text{lx}\cdot\text{s})$
- Simultaneous charge integration for all pixels
- Variable integration time function (electronic shutter function)
- 5 V single power supply operation
- Built-in timing generator allows operation with only start and clock pulse inputs.
- Video data rate: 10 MHz max.

Applications

- Position detection
- Image reading
- Encoders
- Spectrometers

Structure

Parameter	Specification	Unit
Number of pixels	4096	-
Pixel size	7×200	μm
Photosensitive area length	28.672	mm
Package	LCP (liquid crystal polymer)	-
Window material	Quartz	-

Absolute maximum ratings

Parameter	Symbol	Condition	Value	Unit
Supply voltage	Vdd	Ta=25 °C	-0.3 to +6	V
Clock pulse voltage	V(CLK)	Ta=25 °C	-0.3 to +6	V
Start pulse voltage	V(ST)	Ta=25 °C	-0.3 to +6	V
Operating temperature	Topr	No dew condensation*1	-40 to +65	°C
Storage temperature	Tstg	No dew condensation*1	-40 to +65	°C

*1: When there is a temperature difference between a product and the surrounding area in high humidity environments, dew condensation may occur on the product surface. Dew condensation on the product may cause deterioration in characteristics and reliability.

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Recommended terminal voltage (Ta=25 °C)

Parameter	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	Vdd	4.75	5	5.25	V
Clock pulse voltage	High level	3	Vdd	Vdd + 0.25	V
	Low level	0	-	0.3	V
Start pulse voltage	High level	3	Vdd	Vdd + 0.25	V
	Low level	0	-	0.3	V

Input terminal capacitance (Ta=25 °C, Vdd=5 V)

Parameter	Symbol	Min.	Typ.	Max.	Unit
Clock pulse input terminal capacitance	C(CLK)	-	5	-	pF
Start pulse input terminal capacitance	C(ST)	-	5	-	pF

Electrical characteristics [Ta=25 °C, Vdd=5 V, V(CLK)=V(ST)=5 V]

Parameter	Symbol	Min.	Typ.	Max.	Unit
Clock pulse frequency	f(CLK)	200 k	5 M	10 M	Hz
Data rate	DR	-	f(CLK)	-	Hz
Output impedance	Zo	70	-	260	Ω
Current consumption*2 *3	Ic	20	40	60	mA

*2: f(CLK)=10 MHz

*3: Current consumption increases as the clock pulse frequency increases. The current consumption is 10 mA typ. at f(CLK)=200 kHz.

Electrical and optical characteristics [Ta=25 °C, Vdd=5 V, V(CLK)=V(ST)=5 V, f(CLK)=10 MHz]

Parameter	Symbol	Min.	Typ.	Max.	Unit
Spectral response range	λ	200 to 1000			nm
Peak sensitivity wavelength	λ_p	-	700	-	nm
Photosensitivity*4	S	-	650	-	V/(lx·s)
Conversion efficiency*5	CE	-	20	-	$\mu\text{V}/e^-$
Dark output voltage*6	Vd	0	0.1	2	mV
Saturation output voltage*7*8	Vsat	1.5	2.0	2.5	V
Readout noise	Nread	0.1	0.4	1.2	mV rms
Dynamic range 1*9	Drange1	-	5000	-	times
Dynamic range 2*10	Drange2	-	20000	-	times
Output offset voltage	Voffset	0.3	0.6	0.9	V
Photoresponse nonuniformity*4 *11	PRNU	-	±2	±10	%
Image lag*12	Lag	-	-	0.1	%

*4: Measured with a tungsten lamp of 2856 K

*5: Output voltage generated per one electron

*6: Integration time=10 ms

*7: Difference from Voffset

*8: CDS (correlated double sampling) is done inside the image sensor in order to reduce noise. The final output is the difference between the output when the photosensitive area is put in the reset state, and the light output integrated in the photosensitive area. If used in an over-saturated state, the light output component may get mixed into the output when the photosensitive area is put in the reset state, causing the final output to decrease.

*9: $\text{Drange1} = \text{Vsat}/\text{Nread}$

*10: $\text{Drange2} = \text{Vsat}/\text{Vd}$
Integration time=10 ms

Dark output voltage is proportional to the integration time and so the shorter the integration time, the wider the dynamic range.

*11: Photoresponse nonuniformity (PRNU) is the output nonuniformity that occurs when the entire photosensitive area is uniformly illuminated by light which is 50% of the saturation exposure level. PRNU is measured using 4090 pixels excluding 3 pixels each at both ends, and is defined as follows:

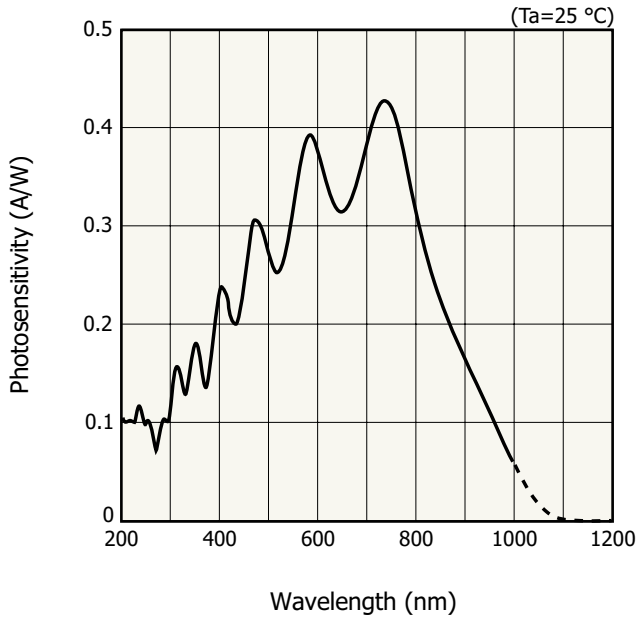
$$\text{PRNU} = \frac{\Delta X}{X} \times 100 (\%)$$

X: average output of all pixels, ΔX : difference between X and maximum output or minimum output

*12: Signal components of the preceding line data that still remain even after the data is read out in a saturation output state.

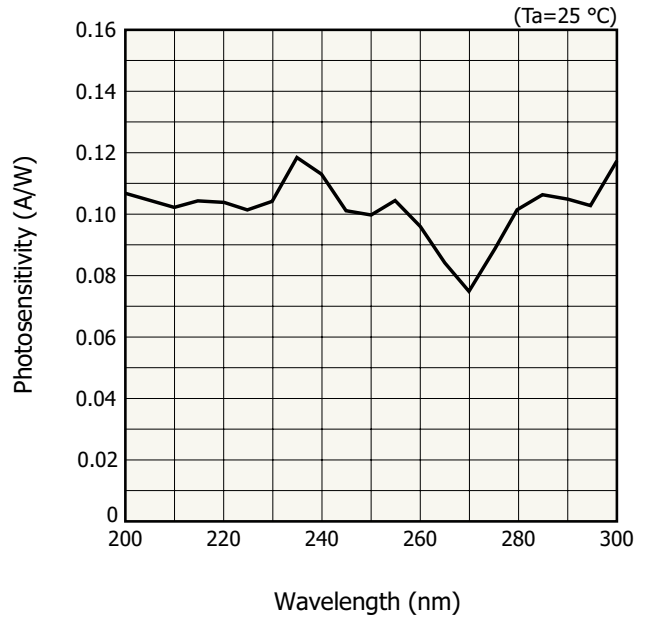
Image lag increases when the output exceeds the saturation output voltage.

Spectral response (typical example)



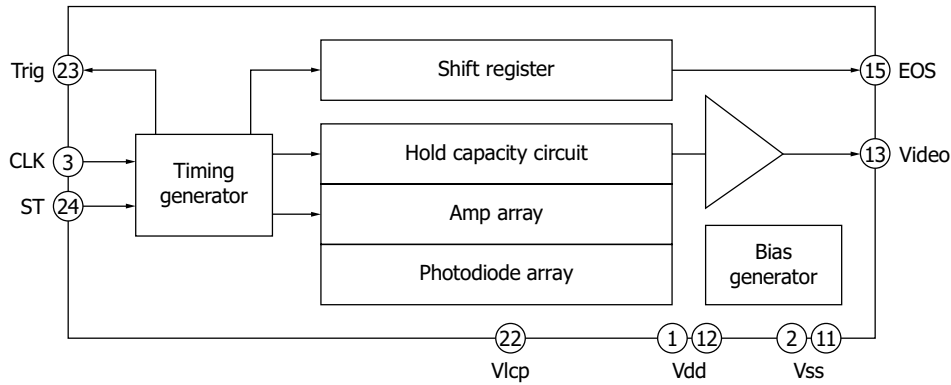
KMPDB0467EB

Spectral response in UV (typical example)



KMPDB0472EA

Block diagram

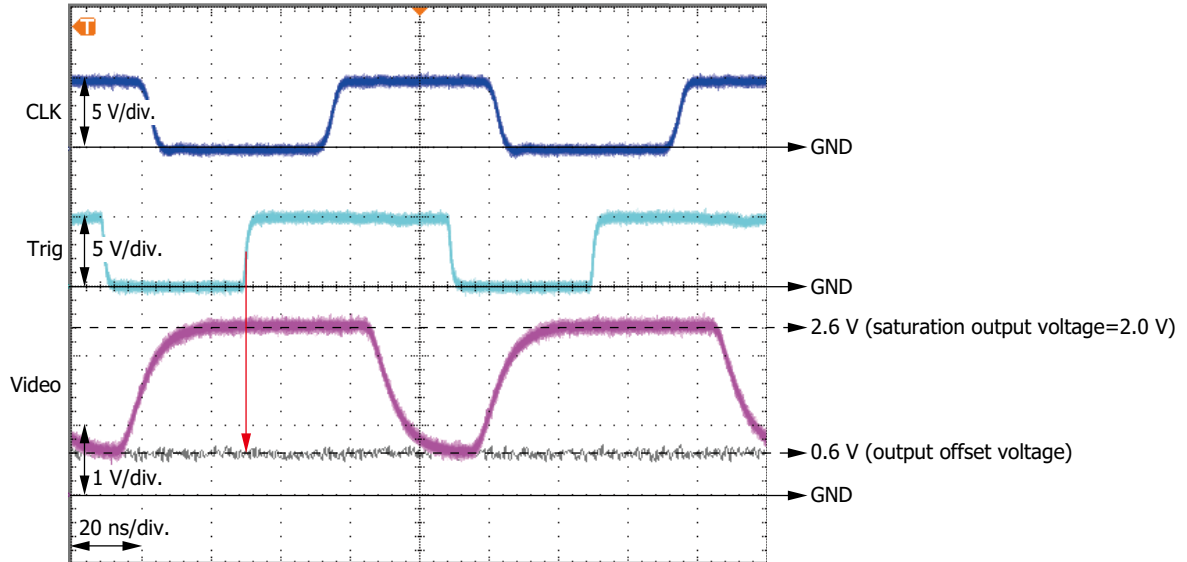


KMPDC0563EA

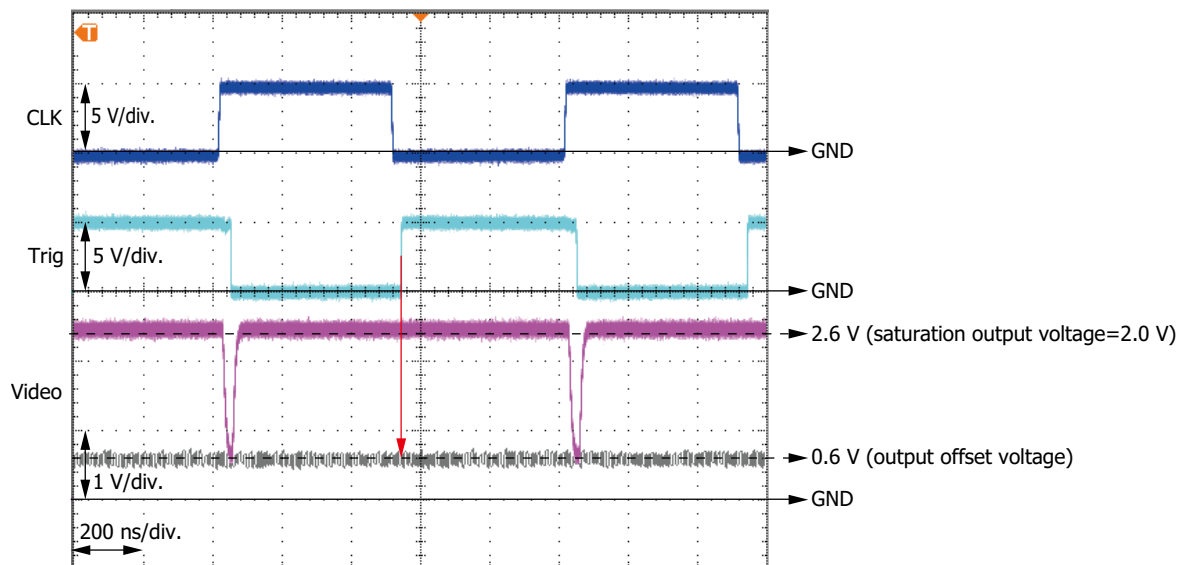
Output waveforms of one pixel

The timing for acquiring the Video signal is synchronized with the rising edge of Trig pulse (See red arrow below.).

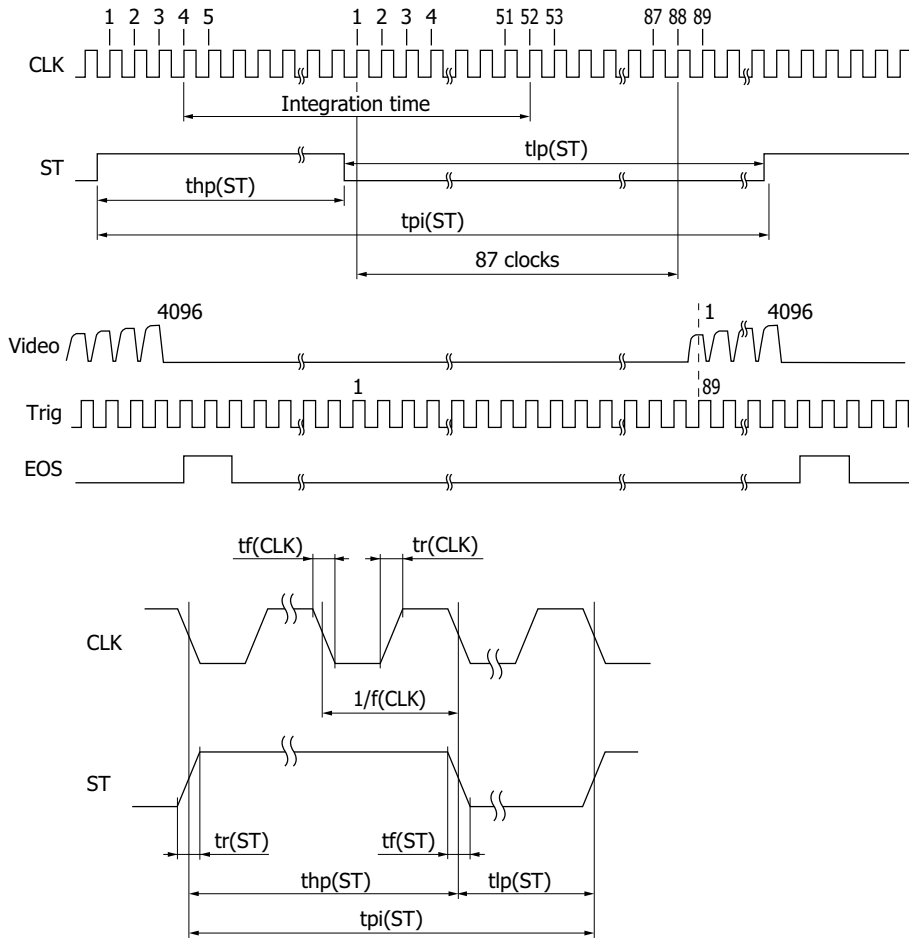
$f(\text{CLK})=\text{DR}=10\text{ MHz}$



$f(\text{CLK})=\text{DR}=1\text{ MHz}$



Timing chart



KMPDC0480EA

Parameter	Symbol	Min.	Typ.	Max.	Unit
Start pulse cycle*13	$t_{pi}(ST)$	$106/f(CLK)$	-	-	s
Start pulse high period*13 *14	$t_{hp}(ST)$	$6/f(CLK)$	-	-	s
Start pulse low period	$t_{lp}(ST)$	$100/f(CLK)$	-	-	s
Start pulse rise and fall times	$t_r(ST), t_f(ST)$	0	10	30	ns
Clock pulse duty ratio	-	45	50	55	%
Clock pulse rise and fall times	$t_r(CLK), t_f(CLK)$	0	10	30	ns

*13: Dark output increases if the start pulse cycle or the start pulse high period is lengthened.

*14: The integration time equals the high period of ST plus 48 CLK cycles.

The shift register starts operation at the rising edge of CLK immediately after ST goes low.

The integration time can be changed by changing the ratio of the high and low periods of ST.

If the first Trig pulse after ST goes low is counted as the first pulse, the Video signal is acquired at the rising edge of the 89th Trig pulse.

Note: After power-on, do not float the ST and CLK input terminals. Instead, set them to high level or low level. Immediately after power-on, the signal in the sensor becomes undefined. Do not use invalid data from the first scan. Instead, use valid data from the second scan onwards.

Operation example

- When outputting from all 4096 pixels

This example assumes that the clock pulse frequency is maximized (data rate is also maximized), the time of one scan is minimized, and the integration time is maximized

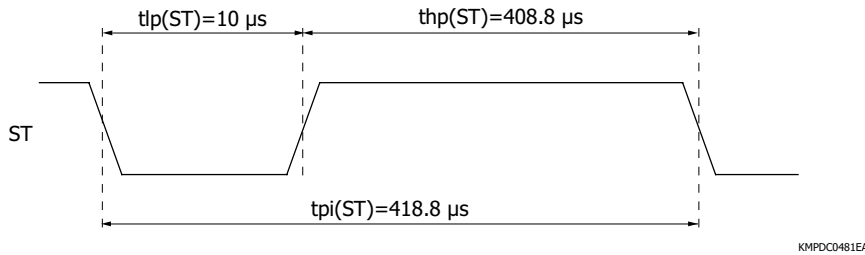
Clock pulse frequency = Data rate = 10 MHz

Start pulse cycle = $4188/f(\text{CLK}) = 4188/10 \text{ MHz} = 418.8 \mu\text{s}$

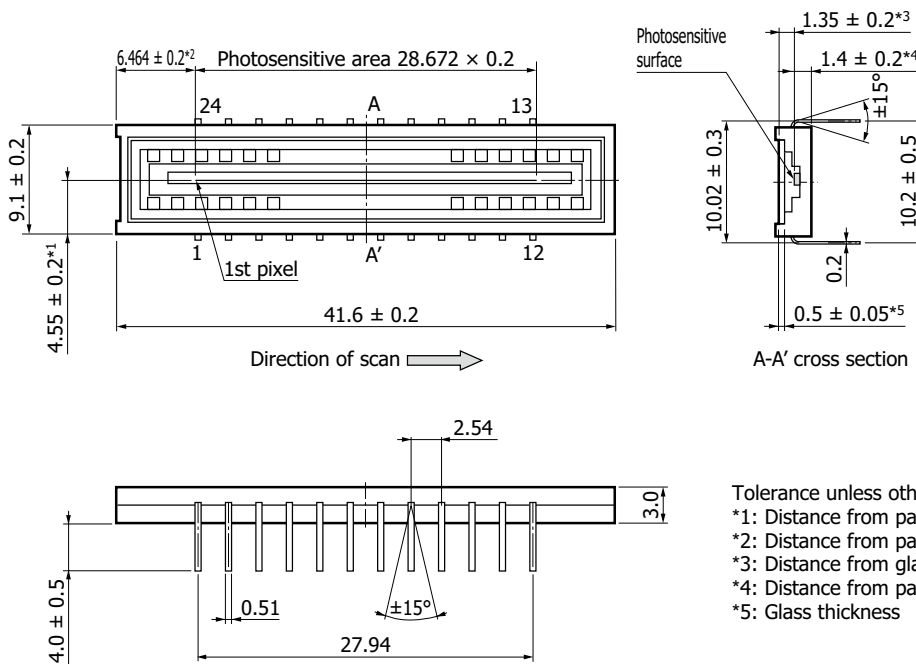
High period of start pulse = Start pulse cycle - Start pulse's low period min.

$$= 4188/f(\text{CLK}) - 100/f(\text{CLK}) = 4188/10 \text{ MHz} - 100/10 \text{ MHz} = 408.8 \mu\text{s}$$

Integration time is equal to the high period of start pulse + 48 cycles of clock pulses, so it will be $408.8 + 4.8 = 413.6 \mu\text{s}$.



Dimensional outline (unit: mm)



- Tolerance unless otherwise noted: ± 0.1
- *1: Distance from package edge to photosensitive area center
 - *2: Distance from package edge to photosensitive area edge
 - *3: Distance from glass surface to photosensitive surface
 - *4: Distance from package bottom to photosensitive surface
 - *5: Glass thickness

Pin connections

Pin no.	Symbol	I/O	Description	Pin no.	Symbol	I/O	Description
1	Vdd	I	Supply voltage	13	Video	O	Video signal*15
2	Vss	-	GND	14	NC	-	No connection
3	CLK	I	Clock pulse	15	EOS	O	End of scan
4	NC	-	No connection	16	NC	-	No connection
5	NC	-	No connection	17	NC	-	No connection
6	NC	-	No connection	18	NC	-	No connection
7	NC	-	No connection	19	NC	-	No connection
8	NC	-	No connection	20	NC	-	No connection
9	NC	-	No connection	21	NC	-	No connection
10	NC	-	No connection	22	Vlcp	-	Bias voltage for negative voltage circuit*16
11	Vss	-	GND	23	Trig	O	Trigger pulse for video signal acquisition*17
12	Vdd	I	Supply voltage	24	ST	I	Start pulse

*15: Connect a buffer amplifier for impedance conversion to the video output terminal so as to minimize the current flow. As the buffer amplifier, use a high input impedance operational amplifier with JFET or CMOS input.

*16: Approximately -1.5 V generated by the negative voltage circuit inside the chip is output to the terminal. To maintain the voltage, insert a capacitor around 1 μ F between Vlcp and GND.

*17: We recommend capturing video signal using the trigger pulse output from Trig.

Note: Leave the "NC" terminals open and do not connect them to GND.

Recommended soldering conditions

Parameter	Specification	Remarks
Solder temperature	260 °C max. (less than 5 s)	

Note: When setting the soldering conditions, check for any problems by testing out the soldering methods in advance.

Precautions

(1) Electrostatic countermeasures

This device has a built-in protection circuit against static electrical charges. However, to prevent destroying the device with electrostatic charges, take countermeasures such as grounding yourself, the workbench and tools. Also protect this device from surge voltages which might be caused by peripheral equipment.

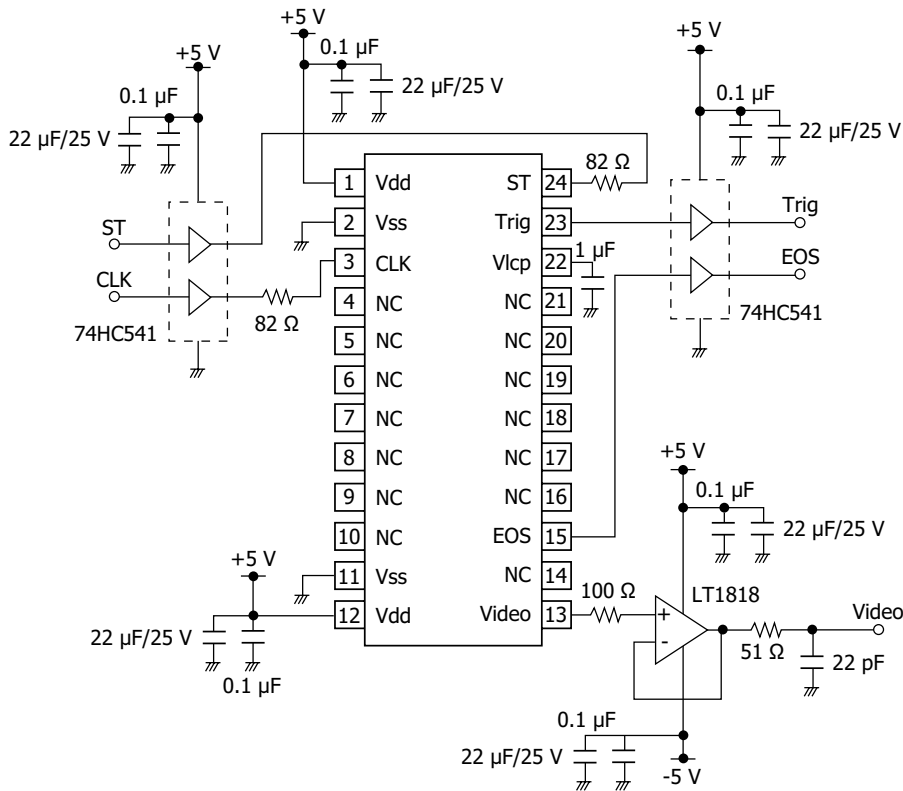
(2) Light input window

If dust or dirt gets on the light input window, it will show up as black blemishes on the image. When cleaning, avoid rubbing the window surface with dry cloth or dry cotton swab, since doing so may generate static electricity. Use soft cloth, paper or a cotton swab moistened with alcohol to wipe dust and dirt off the window surface. Then blow compressed air onto the window surface so that no spot or stain remains.

(3) UV light irradiation

This device is designed to suppress performance deterioration due to UV exposure. Even so, avoid unnecessary UV exposure to the device. Also, be careful not to allow UV light to strike the cemented portion of the glass.

Application circuit example



KMPDC0564EA

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
 - Disclaimer
 - Image sensors
- Technical note
 - CMOS linear image sensors

Driver circuit for CMOS linear image sensors C16605 [sold separately]

The driver circuit for CMOS linear image sensor S13496 is available (sold separately). It can be used for spectrometers, etc. combining with the CMOS linear image sensor. Contact us for detailed information.



Features

- Built-in 16-bit A/D converter
- Interface to computer: USB 2.0
- Power supply: USB bus power operation

Information described in this material is current as of April 2024.

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